

## NCE2007N

### SNCE N-Channel Enhancement Mode Power MOSFET

### **Description**

The NCE2007N uses advanced trench technology to provide excellent R<sub>DS(ON)</sub>, low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a Battery protection or in other Switching application.

#### **General Features**

•  $V_{DS} = 20V, I_D = 6.5A$ 

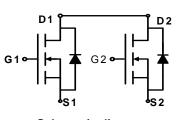
 $R_{DS(ON)}$  < 27m $\Omega$  @  $V_{GS}$ =2.5V

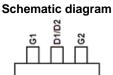
 $R_{DS(ON)}$  < 22m $\Omega$  @  $V_{GS}$ =4.5V

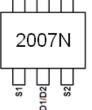
- High power and current handing capability
- Lead free product is acquired
- Surface mount package

## **Application**

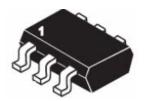
- Battery protection
- Load switch
- Power management







Marking and pin assignment



SOT23-6L top view

#### Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
2007N	NCE2007N	SOT23-6L	Ø330mm	12mm	3000 units

#### Absolute Maximum Ratings (T<sub>A</sub>=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	V <sub>DS</sub>	20	V	
Gate-Source Voltage	V <sub>GS</sub>	±12	V	
Drain Current-Continuous	I <sub>D</sub>	6.5	А	
Drain Current-Pulsed (Note 1)	I <sub>DM</sub>	25	А	
Maximum Power Dissipation	P <sub>D</sub>	1.5	W	
Operating Junction and Storage Temperature Range	$T_{J}, T_{STG}$	-55 To 150	°C	

#### **Thermal Characteristic**

Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{ heta JA}$	83	°C/W
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#### Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						



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## **NCE2007N**

Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	20	-	ı	>
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$I_{DSS}$ $V_{DS}$ =20V, $V_{GS}$ =0V		-	1	μΑ
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±12V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =250μA	0.5	0.7	1.2	V
Drain-Source On-State Resistance	В	V <sub>GS</sub> =4.5V, I <sub>D</sub> =6A	-	14.5	22	mΩ
Dialii-Source Oil-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =2.5V, I <sub>D</sub> =5.5A	-	19	27	mΩ
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =5V,I <sub>D</sub> =6A	-	10	ı	S
Dynamic Characteristics (Note4)						
Input Capacitance	C <sub>lss</sub>	\/ -10\/\/ -0\/	-	900	-	PF
Output Capacitance	C <sub>oss</sub>	$V_{DS}$ =10V, $V_{GS}$ =0V, F=1.0MHz	-	220	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F = 1.0IVII 12	-	100	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t <sub>d(on)</sub>		-	10	20	nS
Turn-on Rise Time	t <sub>r</sub>	V <sub>DD</sub> =10V,I <sub>D</sub> =6A	-	11	25	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =4.5 $V$ , $R_{GEN}$ =6 $\Omega$	-	35	70	nS
Turn-Off Fall Time	t <sub>f</sub>		-	30	60	nS
Total Gate Charge	Qg	\/ =10\/   =6A	-	12	15	nC
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}$ =10V, $I_{D}$ =6A, $V_{GS}$ =4.5V	-	2.3	-	nC
Gate-Drain Charge	$Q_{gd}$	VGS-4.5V	-	1	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =6A	-	-	1.2	V
Diode Forward Current (Note 2)	I <sub>S</sub>		-	-	6.5	Α

#### Notes:

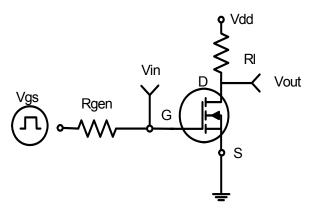
- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- **3.** Pulse Test: Pulse Width ≤  $300\mu$ s, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production



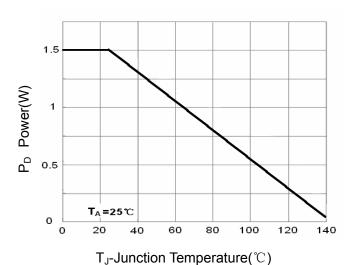
# **NCE2007N**

**Pb Free Product** 

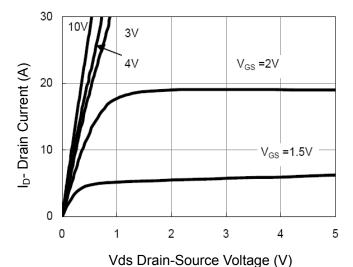
## **Typical Electrical and Thermal Characteristics**



**Figure 1:Switching Test Circuit** 



**Figure 3 Power Dissipation** 



**Figure 5 Output Characteristics** 

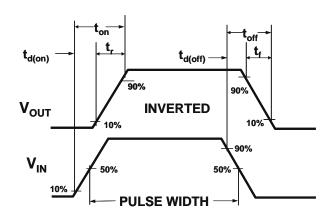
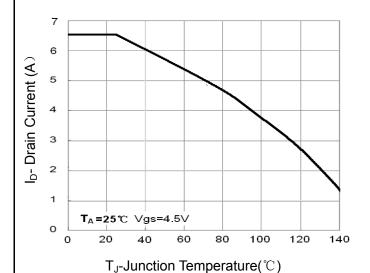


Figure 2:Switching Waveforms



**Figure 4 Drain Current** 

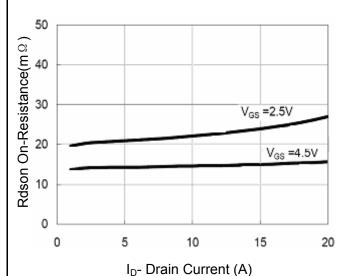
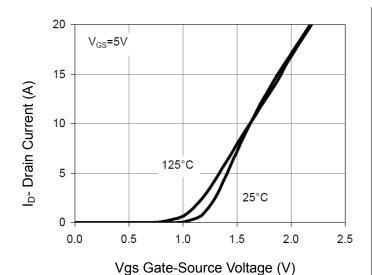


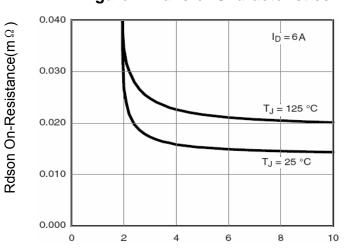
Figure 6 Drain-Source On-Resistance







**Figure 7 Transfer Characteristics** 



Vgs Gate-Source Voltage (V) Figure 9 Rdson vs Vgs

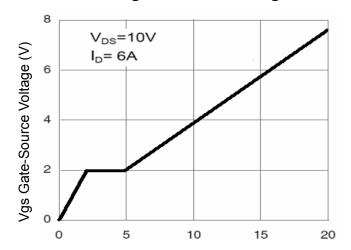


Figure 11 Gate Charge

Qg Gate Charge (nC)

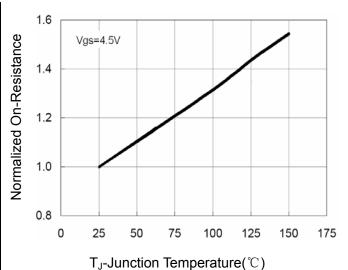
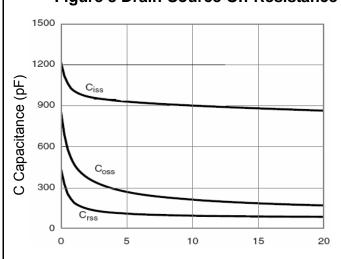
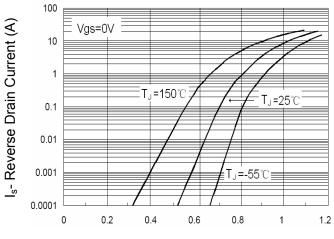


Figure 8 Drain-Source On-Resistance



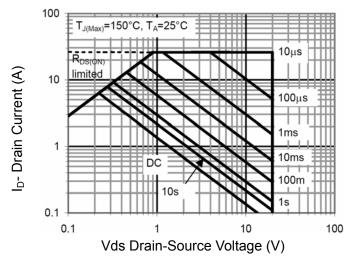
Vds Drain-Source Voltage (V) Figure 10 Capacitance vs Vds



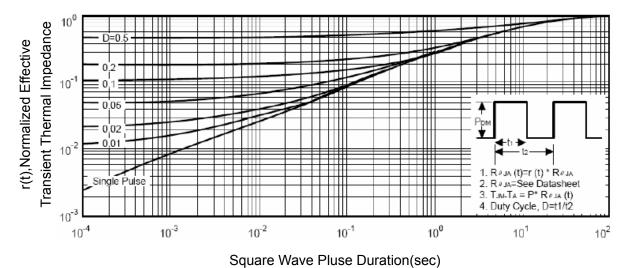
Vsd Source-Drain Voltage (V)

Figure 12 Source- Drain Diode Forward





**Figure 13 Safe Operation Area** 

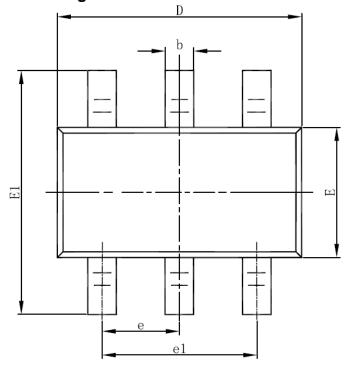


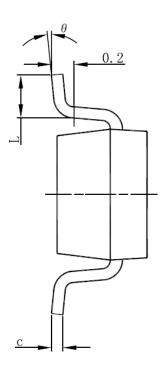
**Figure 14 Normalized Maximum Transient Thermal Impedance** 

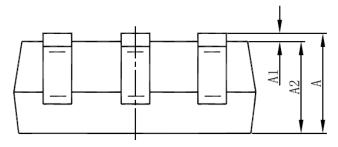


## NCE2007N

## **SOT23-6L Package Information**







Cl	Dimensions Ir	n Millimeters	Dimensions In Inches		
Symbol	Min	Max	Min	Max	
Α	1.050	1.250	0.041	0.049	
A1	0.000	0.100	0.000	0.004	
A2	1.050	1.150	0.041	0.045	
b	0.300	0.500	0.012	0.020	
С	0.100	0.200	0.004	0.008	
D	2.820	3.020	0.111	0.119	
E	1.500	1.700	0.059	0.067	
E1	2.650	2.950	0.104	0.116	
е	0.950	(BSC)	0.037(BSC)		
e1	1.800	2.000	0.071	0.079	
L	0.300	0.600	0.012	0.024	
θ	0°	8°	0°	8°	



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